

Features

- ESD Protected Up To 2KV (HBM)
- High Dense Cell Design For Extremely Low RDS(ON)
- Moisture Sensitivity Level 1
- Halogen Free. "Green" Device (Note 1)
- Epoxy Meets UL 94 V-0 Flammability Rating
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

Maximum Ratings

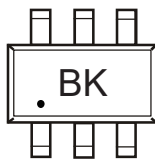
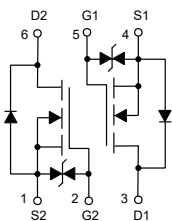
- Operating Junction Temperature Range: -55°C to +150°C
- Storage Temperature: -55°C to +150°C
- Thermal Resistance: 357°C/W Junction to Ambient^(Note2)

Parameter	Symbol	Rating	Unit
Drain-Source Voltage	V _{DS}	50	V
Gate-Source Voltage	V _{GS}	±20	V
Continuous Drain Current	I _D	T _A =25°C	0.22
		T _A =70°C	0.17
Pulsed Drain Current ^(Note 3)	I _{DM}	0.88	A
Total Power Dissipation ^(Note 4)	P _D	0.35	W

Note:

1. Halogen free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
2. The value of R_{θJA} is measured with the device mounted on 1in² FR-4 board with 2oz. Copper, in a still air environment with T_A=25°C.
3. Repetitive rating; pulse width limited by max. junction temperature.
4. P_D is based on max. junction temperature, using junction-ambient thermal resistance.

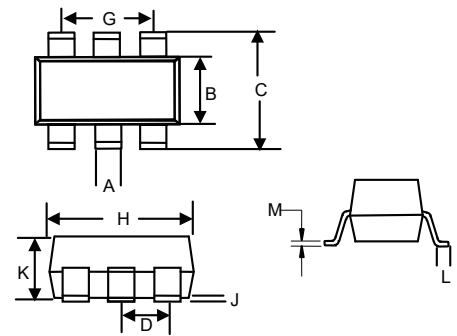
Internal Structure and Marking Code



Dot denotes Pin1

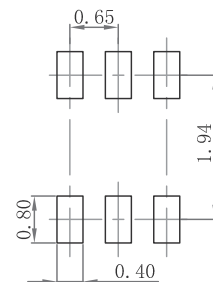
Dual N-Channel MOSFET

SOT-363



DIM	INCHES		MM		NOTE
	MIN	MAX	MIN	MAX	
A	0.006	0.014	0.15	0.35	
B	0.045	0.053	1.15	1.35	
C	0.079	0.096	2.00	2.45	
D	0.026		0.65		TYP.
G	0.047	0.055	1.20	1.40	
H	0.071	0.087	1.80	2.20	
J	-----	0.004	-----	0.10	
K	0.031	0.043	0.80	1.10	
L	0.010	0.018	0.26	0.46	
M	0.003	0.006	0.08	0.15	

Suggested Solder Pad Layout



ELECTRICAL CHARACTERISTICS (Ta=25°C unless otherwise specified)

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Static Characteristics						
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	$V_{GS}=0V, I_D=250\mu A$	50			V
Gate-Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=250\mu A$	0.8	1.0	1.45	V
Gate-Body Leakage Current	I_{GSS}	$V_{GS}=\pm 20V, V_{DS}=0V$			± 10	μA
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS}=48V, V_{GS}=0V$			1	μA
Drain-Source On-Resistance	$R_{DS(on)}$	$V_{GS}=10V, I_D=0.5A$		1	1.5	Ω
		$V_{GS}=4.5V, I_D=0.2A$		1.3	2.3	
		$V_{GS}=2.5V, I_D=0.1A$		2.2	4.1	
Forward Transconductance	g_{FS}	$V_{DS}=10V, I_D=0.2A$		370		mS
Gate Resistance	R_g	f=1 MHz, Open drain		90		Ω
Dynamic Characteristics						
Continuous Body Diode Current	I_S				0.22	A
Diode Forward Voltage	V_{SD}	$V_{GS}=0V, I_S=0.5A$			1.2	V
Reverse Recovery Time	t_{rr}	$I_F=0.3A, dI_F/dt=100A/\mu s$		8		ns
Reverse Recovery Charge	Q_{rr}			2.8		nC
Dynamic Characteristics						
Input Capacitance	C_{iss}	$V_{DS}=25V, V_{GS}=0V, f=1MHz$		25		μF
Output Capacitance	C_{oss}			6		
Reverse Transfer Capacitance	C_{rss}			4		
Total Gate Charge	Q_g	$V_{DS}=25V, V_{GS}=10V, I_D=0.15A$		1.17		nC
Gate-Source Charge	Q_{gs}			0.16		
Gate-Drain Charge	Q_{gd}			0.22		
Turn-On Delay Time	$t_{d(on)}$	$V_{DD}=25V, V_{GS}=10V, R_G=2.5\Omega, I_D=0.3A$		4		ns
Turn-On Rise Time	t_r			3		
Turn-Off Delay Time	$t_{d(off)}$			9		
Turn-Off Fall Time	t_f			6		

Curve Characteristics

Fig.1 - Typical Output Characteristics

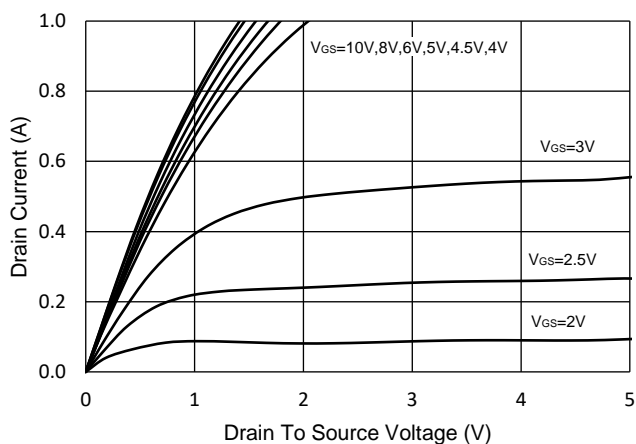


Fig.2 - Transfer Characteristic

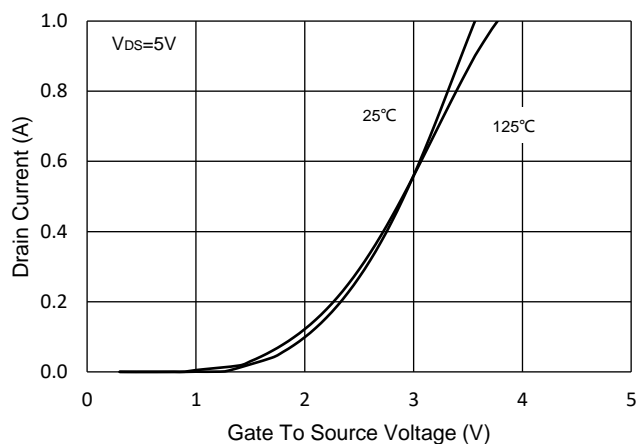


Fig.3 - $R_{DS(ON)}$ - V_{GS}

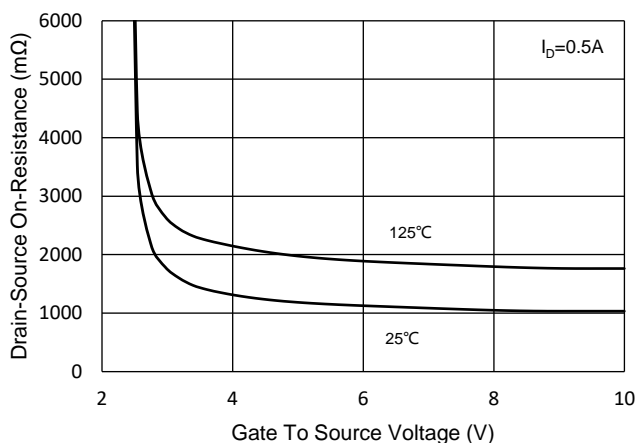


Fig.4 - $R_{DS(ON)}$ - I_D

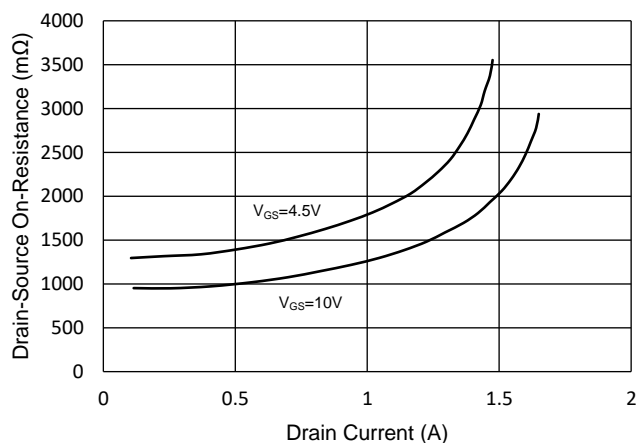


Fig.5 - Capacitance Characteristics

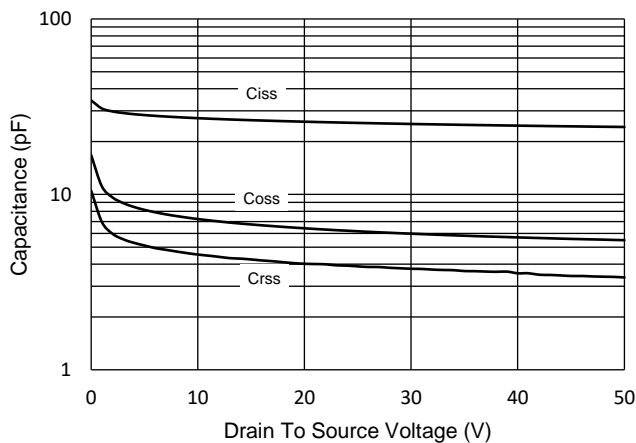
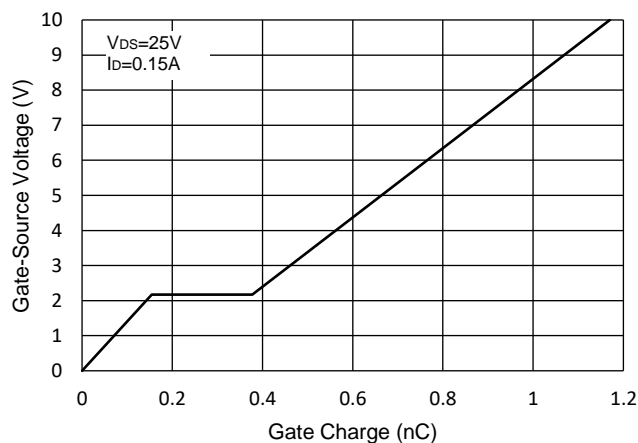


Fig.6 - Gate Charge



Curve Characteristics

Fig.7 - Normalized Threshold Voltage

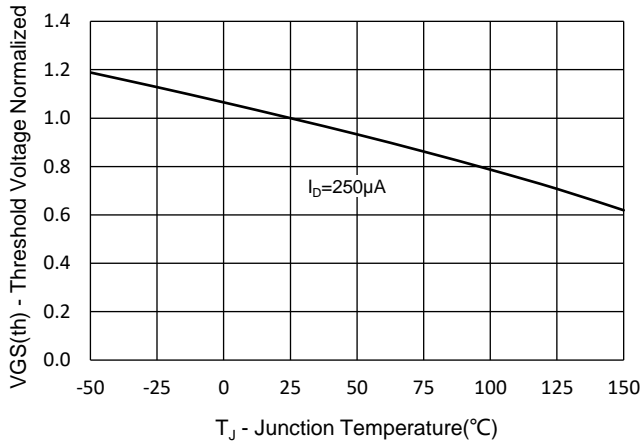


Fig.8 - Normalized On Resistance Characteristics

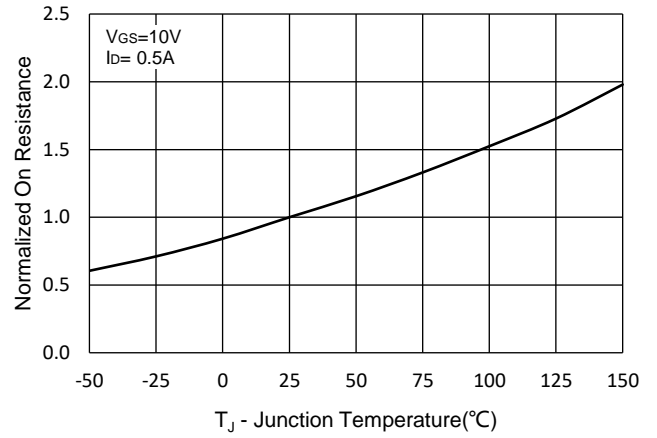


Fig.9 - I_S - V_{SD}

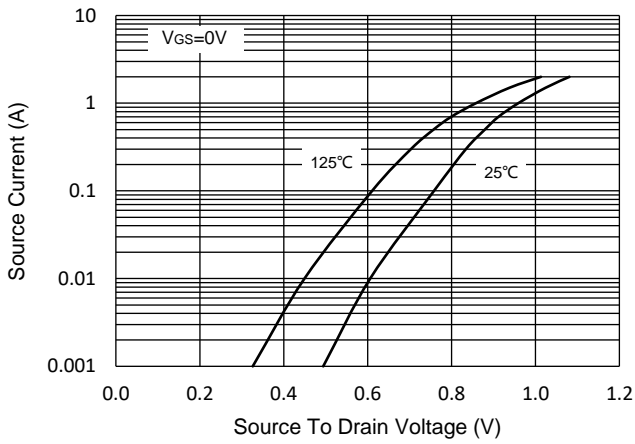


Fig.10 - Drain Current

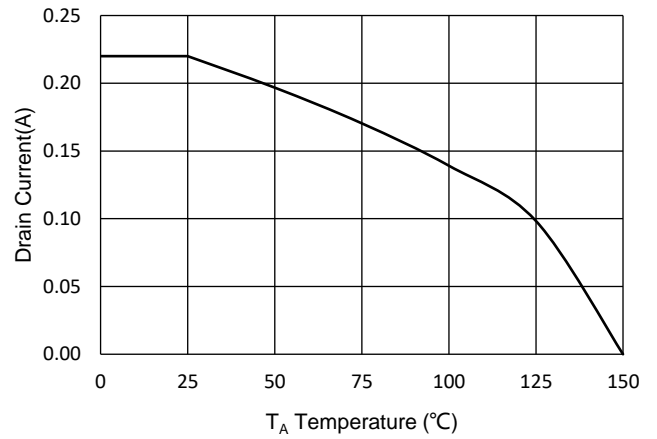
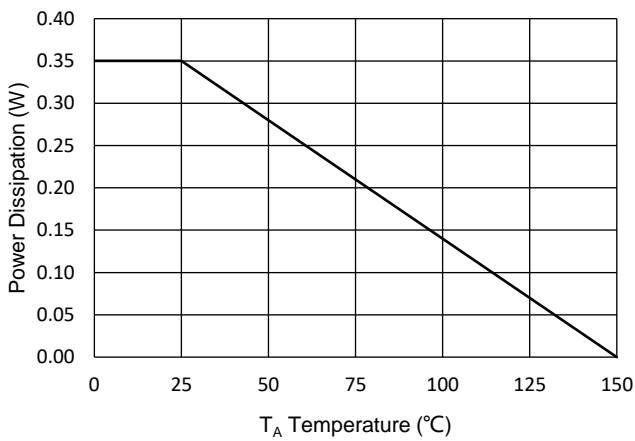


Fig.11 - PD Dissipation



Curve Characteristics

Fig.12 - Safe Operation Area

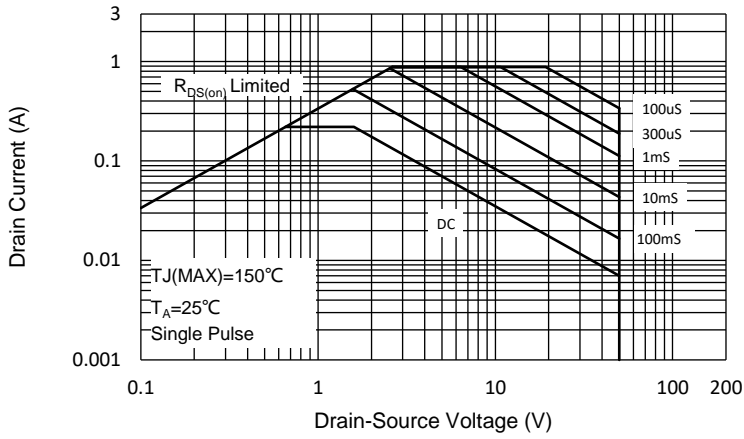
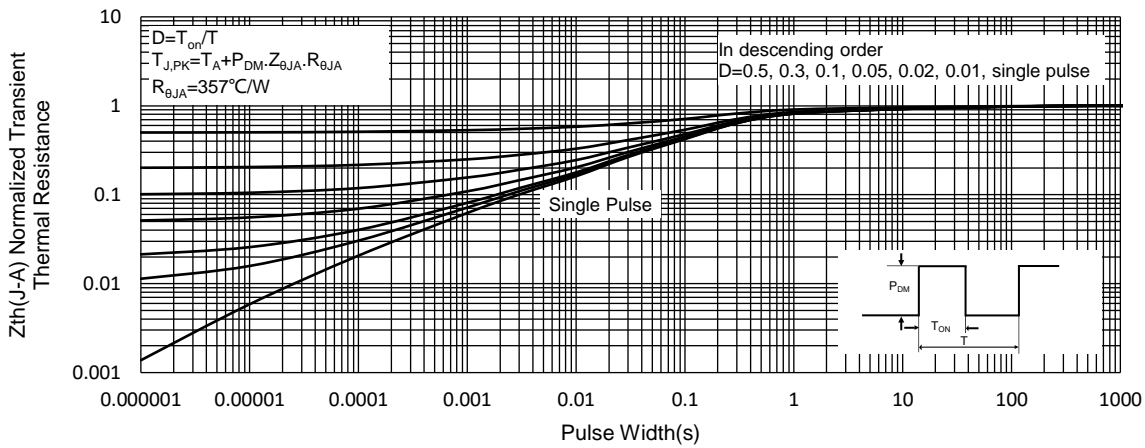


Fig.13 - Normalized Transient Thermal Impedance



Ordering Information

Device	Packing
Part Number-TP	Tape&Reel:3Kpcs/Reel
Part Number-TPQ2	Tape&Reel:3Kpcs/Reel

For packaging details, go to our website at <https://www.mccsemi.com/pdf/ProductPackaging/SOT-363%20Package.pdf>

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